

Monolithic Amplifier

Mini-Circuits

50Ω DC to 6 GHz

THE BIG DEAL

- Gain, 10 dB typ.
- High Pout, P1dB 19.5 dBm typ.
- High IP3, 41 dBm typ. at 1 GHz
- Ruggedized design
- Fixed 5V operation
- Unconditionally stable
- Excellent ESD Protection
- Transient protected, US patent 6,943,629
- Low additive phase noise, typically -171 dBc/Hz @10 KHz



Generic photo used for illustration purposes only

CASE STYLE: DF782

+RoHS Compliant The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

LTE Performance

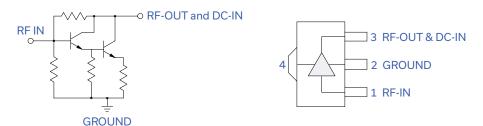
APPLICATIONS

- Base station infrastructure
- Portable Wireless
- CATV & DBS
- MMDS & Wireless LAN
- LTE
- Suitable for low phase noise applications

PRODUCT OVERVIEW

GVA-81+ (RoHS compliant) is a wideband amplifier offering high dynamic range. It has repeatable performance from lot to lot and is enclosed in a SOT-89 package. It uses patented Transient Protected Darlington configuration and is fabricated using InGaP HBT technology.

SIMPLIFIED SCHEMATIC AND PIN DESCRIPTION



| Function | Pin Number | Description |
|---------------------|---------------|---|
| RF IN | 1 | RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation. |
| RF-OUT and DC-IN | 3 | RF output and bias pin. DC voltage is present on this pin; therefore a DC blocking capacitor is necessary for proper operation. An RF choke is needed to feed DC bias without loss of RF signal due to the bias connection, as shown in "Recommended Application Circuit", Fig. 2 |
| GND | 2,4 | Connections to ground. Use via holes as shown in "Suggested Layout for PCB Design" to reduce ground path inductance for best performance. |

A. Suitability for model replacement within a particular system must be determined by and is solely the responsibility of the customer based on, among other things, electrical performance criteria, stimulus conditions, application, compatibility with other components and environmental conditions and stresses. B. The RFMD SBB4089Z part number is used for identification and comparison purposes only.

> REV. C ECO-010563 GVA-81+ 211108

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ELECTRICAL SPECIFICATIONS⁽¹⁾ AT 25°C AND 5V, UNLESS NOTED

| Parameter | Condition (GHz) | Min. | Тур. | Max. | Units |
|---|-----------------|------|--------|-------|------------|
| Frequency Range ² | | DC | | 6 | GHz |
| | 0.1 | 9.5 | 10.5 | 11.5 | dB |
| | 1.0 | _ | 10.5 | _ | |
| Gain | 2.0 | 9.0 | 10.0 | 11.0 | |
| | 3.0 | _ | 9.3 | _ | |
| | 4.0 | 8.0 | 8.7 | 10.0 | |
| | 6.0 | _ | 8.1 | _ | |
| | 0.1 | _ | 0.0005 | _ | dB/°C |
| | 1.0 | _ | 0.0010 | _ | |
| npMagnitude of Gain Variation versus Temperature ⁽³⁾ | 2.0 | _ | 0.0016 | 0.005 | |
| values are negative) | 3.0 | _ | 0.0020 | _ | |
| | 4.0 | _ | 0.0025 | _ | |
| | 6.0 | _ | 0.0036 | _ | |
| | 0.1 | _ | 38.0 | _ | dB |
| | 1.0 | _ | 27.0 | _ | |
| | 2.0 | 17 | 20.1 | _ | |
| nput Return Loss | 3.0 | _ | 17.4 | _ | |
| | 4.0 | _ | 16.9 | _ | |
| | 6.0 | _ | 18.5 | _ | |
| Reverse Isolation | 2.0 | | 20.8 | | dB |
| | 0.1 | 18.0 | 19.1 | _ | dBm |
| | 1.0 | 18.0 | 19.1 | _ | |
| | 2.0 | 18.0 | 19.7 | _ | |
| Output Power at 1dB Compression | 3.0 | _ | 20.0 | _ | |
| | 4.0 | _ | 19.4 | _ | |
| | 6.0 | _ | 17.7 | _ | |
| | 0.1 | _ | 42.0 | _ | dBm |
| | 1.0 | _ | 41.3 | _ | |
| | 2.0 | 34 | 36.6 | _ | |
| Dutput IP3 | 3.0 | _ | 35.0 | _ | |
| | 4.0 | _ | 33.2 | _ | |
| | 6.0 | _ | 31.1 | _ | |
| | 0.1 | _ | 7.3 | 7.9 | |
| | 1.0 | _ | 7.3 | _ | dB |
| | 2.0 | _ | 7.4 | 7.9 | |
| Noise Figure | 3.0 | _ | 7.6 | _ | |
| | 4.0 | _ | 7.7 | 8.2 | |
| | 6.0 | _ | 8.3 | _ | |
| Additive Phase Noise 2 GHz, 10 KHz offset | 5.0 | | -171 | | dBc/Hz |
| Group Delay | | 4.8 | 98 | | psec |
| Device Operating Voltage | | 94 | 5.0 | 5.2 | V |
| Device Operating Current | | 5. | 103 | 112 | mA |
| Device Current Variation vs. Temperature | | | 62 | | µA/°C |
| Device Current Variation vs. Temperature | | | 0.036 | | mA/mV |
| | | | 0.050 | | 111/5/1111 |

Measured on Mini-Circuits test board TB-313. See Characterization Test Circuit (Fig. 1)
Guaranteed specification DC*-7 GHz. *Low frequency cut off determined by external coupling capacitors and RF Choke (RFC).
(Gain at 85°C, Gain at -45°C)/130



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MAXIMUM RATINGS

| Parameter | Ratings | |
|-------------------------------------|----------------|--|
| Operating Temperature (ground lead) | -40°C to 85°C | |
| Storage Temperature | -65°C to 150°C | |
| Operating Current at 5V | 160mA | |
| Power Dissipation | 0.855W | |
| Input Power | 13dBm | |
| DC Voltage on Pin 3 | 5.9V | |

Permanent damage may occur if any of these limits are exceeded.

Electrical maximum ratings are not intended for continuous normal operation.

CHARACTERIZATION TEST CIRCUIT

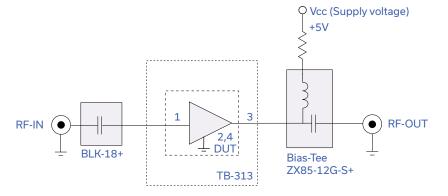


Fig 1. Block Diagram of Test Circuit used for characterization. (DUT soldered on Mini-Circuits Test Board TB-313) Gain, Output power at 1dB compression (P1 dB) and output IP3 (OIP3) are measured using R&S Network Analyzer ZVA-24. Noise Figure measured using Agilent's N5242A PNA-X microwave network analyzer.

Conditions:

1. Gain and Return loss: Pin= -25dBm 2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, 0 dBm/ tone at output.

RECOMMENDED APPLICATION CIRCUIT

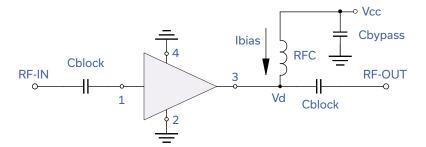


Fig 2. Test Board includes case, connectors, and components soldered to PCB

PRODUCT MARKING



Marking may contain other features or characters for internal lot control

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ADDITIONAL DETAILED TECHNICAL INFORMATION IS AVAILABLE ON OUR DASH BOARD. TO ACCESS CLICK HERE

| | Data Table | |
|--|--|--|
| Performance Data | Swept Graphs | |
| | S-Parameter (S2P Files) Data Set (.zip file) | |
| Case Style | DF782 (SOT 89) Plastic package, exposed paddle lead finish: Matte-tin | |
| Tape & Reel Standard quantities available on reel | F55 7″ reels with 20, 50, 100, 200, 500 or 1K devices | |
| Suggested Layout for PCB Design | PL-255 | |
| Evaluation Board | TB-410-81+ | |
| Environmental Ratings | ENV08T1 | |

ESD RATING

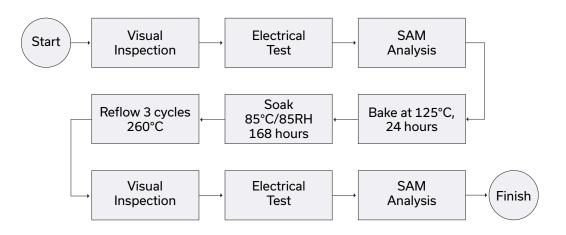
Human Body Model (HBM): Class 1C (1000v to < 2000v) in accordance with ANSI/ESD STM 5.1 - 2001

Machine Model (MM): Class M2 (100V to < 200V) in accordance with ANSI/ESD STM 5.2 - 1999

MSL RATING

Moisture Sensitivity: MSL1 in accordance with IPC/JEDECJ-STD-020D

MSL TEST FLOW CHART



NOTES

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
- C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the standard. Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/MCLStore/terms.jsp

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